MSKSEMI















ESD

TVS

TSS

MOV

GDT

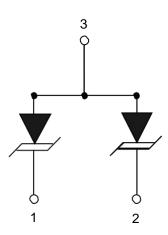
PLED

Broduct data sheet





SOT-523



Features

45 Watts peak pulse power (tp = $8/20\mu s$)

Unidirectional configurations

Solid-state silicon-avalanche technology

Low clamping voltage

Low leakage current

Low capacitance (C_j=0.7 pF typ.)

Protection two data lines

IEC 61000-4-2 \pm 20kV contact \pm 15kV air

IEC 61000-4-4 (EFT) 40A(5/50ns)

IEC 61000-4-5 (Lightning) 3.5A (8/20μs)

Mechanical Data

SOT-523

Molding compound flammability rating: UL 94V-0

Packaging: Tape and Reel RoHS/WEEE Compliant

Applications

Dataline

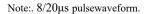
Automatic Teller Machines

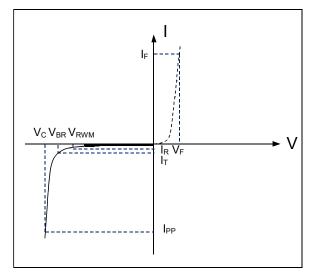
Net works

Power line

Electrical Parameters (TA = 25°C unless otherwisenoted)

| Symbol | Parameter | |
|-------------------|---|--|
| Ірр | Maximum Reverse Peak Pulse Current | |
| Vc | Clamping Voltage @ Ipp | |
| V _{RW M} | Working Peak Reverse Voltage | |
| Ir | Maximum Reverse Leakage Current @ VRW M | |
| $ m V_{BR}$ | Breakdown Voltage @ IT | |
| Iт | Test Current | |
| | | |
| | | |





Absolute Maximum Rating

| Rating | Symbol | Value | Units |
|---|-----------------|----------------|------------|
| Peak Pulse Power (t _p =8/20μs) | P _{PP} | 45 | Watts |
| Peak Pulse Current (t _p =8/20μs)(note1) | I_{pp} | 3.5 | A |
| ESD per IEC 61000-4-2(Air) ESD per IEC 61000-4-2 (Contact) | V_{ESD} | 20 15 | kV |
| Lead SolderingTemperature | $T_{ m L}$ | 260(10seconds) | $^{\circ}$ |
| JunctionTemperature | TJ | -55 to + 125 | $^{\circ}$ |
| StorageTemperature | $T_{ m stg}$ | -55 to + 125 | $^{\circ}$ |

Electrical Characteristics

| Parameter | Symbol | Conditions | Min | Typical | Max | Units |
|--------------------------|-------------------|-------------------------------|-----|---------|-----|-------|
| Reverse Stand-OffVoltage | $V_{ m RWM}$ | | | | 5 | V |
| Reverse BreakdownVoltage | $ m V_{BR}$ | I _T =1mA | 6 | | | V |
| Reverse LeakageCurrent | I_R | V _{RWM} =5V,T=25°C | | | 1 | μΑ |
| Peak Pulse Current | I_{PP} | tp =8/20μs | | | 3.5 | A |
| Clamping Voltage | V _C | $I_{PP}=3.5A, t_p=8/20 \mu s$ | | | 25 | V |
| JunctionCapacitance | C _j | $V_R = 0V, f = 1MHz$ | | 0.7 | 0.8 | pF |

TypicalCharacteristics

Figure 1: Peak Pulse Power vs. Pulse Time

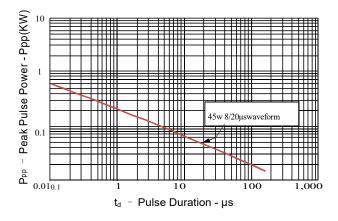


Figure 2: Power Derating Curve

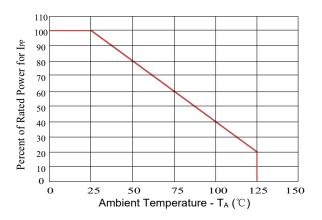


Figure3: Pulse Waveform

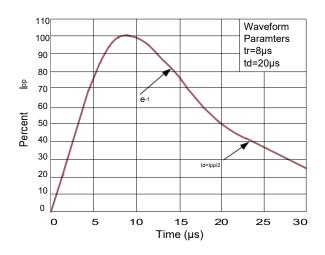
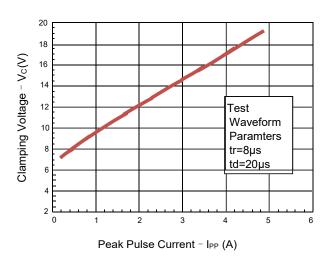
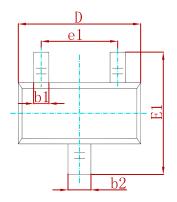


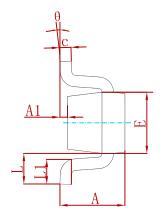
Figure 4: Clamping Voltage vs.lpp

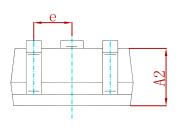




PACKAGE MECHANICAL DATA

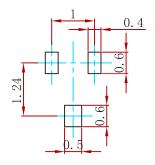






| Comple ed | Dimensions In Millimeters | | Dimensions In Inches | |
|-----------|---------------------------|-------|----------------------|-------|
| Symbol | Min. | Max. | Min. | Max. |
| Α | 0.700 | 0.900 | 0.028 | 0.035 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 0.700 | 0.800 | 0.028 | 0.031 |
| b1 | 0.150 | 0.250 | 0.006 | 0.010 |
| b2 | 0.250 | 0.350 | 0.010 | 0.014 |
| С | 0.100 | 0.200 | 0.004 | 0.008 |
| D | 1.500 | 1.700 | 0.059 | 0.067 |
| E | 0.700 | 0.900 | 0.028 | 0.035 |
| E1 | 1.450 | 1.750 | 0.057 | 0.069 |
| е | 0.500 TYP. | | 0.020 | TYP. |
| e1 | 0.900 | 1.100 | 0.035 | 0.043 |
| L | 0.400 | REF. | 0.016 | REF. |
| L1 | 0.260 | 0.460 | 0.010 | 0.018 |
| θ | 0° | 8° | 0° | 8° |

Suggested Pad Layout



Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

| P/N | PKG | QTY |
|----------------|---------|------|
| RCLAMP0502B-MS | SOT-523 | 3000 |



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